

BC337-16-5 Transistors

Si NPN Lo-Pwr BJT

Military/High-Rel N

V(BR)CEO (V) 45

V(BR)CBO (V) 50

I(C) Max. (A) 800m

Absolute Max. Power Diss. (W) 600m

Maximum Operating Temp (°C) 150°

I(CBO) Max. (A) 100nØ

@V(CBO) (V) (Test Condition)

V(CE)sat Max. (V)

@I(C) (A) (Test Condition)

@I(B) (A) (Test Condition)

h(FE) Min. Current gain. 100

h(FE) Max. Current gain.

@I(C) (A) (Test Condition) 100m

@V(CE) (V) (Test Condition) 1.0

f(T) Min. (Hz) Transition Freq 100M

@I(C) (A) (Test Condition)

@V(CE) (V) (Test Condition)

C(obo) (Max) (F) 15p

@V(CB) (V) (Test Condition)

@Freq. (Hz) (Test Condition)